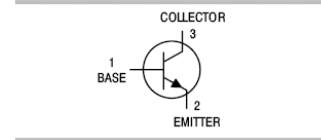




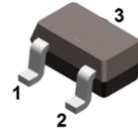
### Features

- Epitaxial planar die construction
- Complementary PNP type available(MMST5401)



### Mechanical Data

- Case: SOT-323
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208



SOT-323

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
MMST5551	SOT-323	3000 pcs / Tape & Reel	K4N

### Maximum Ratings (@ T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	180	V
Collector-Emitter Breakdown Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Breakdown Voltage	V <sub>EBO</sub>	6	V
Collector Current (Continuous)	I <sub>C</sub>	0.6	A
Collector Current (Peak)	I <sub>CM</sub>	0.8	A

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	0.2	W
Thermal Resistance Junction-to-Air	R <sub>θJA</sub>	625	°C/W
Junction Temperature Range	T <sub>J</sub>	-55 ~ +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	°C

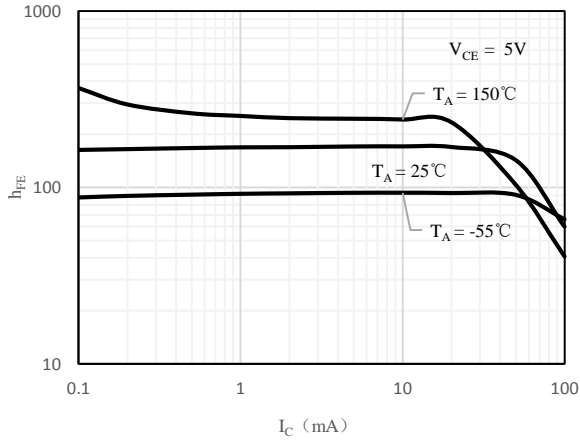


### Electrical Characteristics (@ T<sub>A</sub> = 25°C unless otherwise specified)

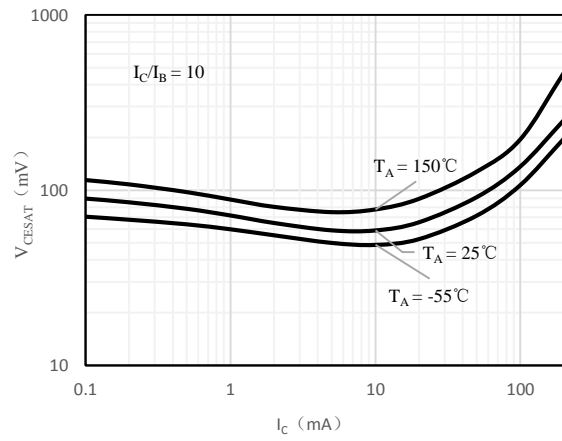
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μA, I <sub>E</sub> = 0	180	-	-	V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 0.1mA, I <sub>B</sub> = 0	160	-	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 10μA, I <sub>C</sub> = 0	6	-	-	V
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0	-	-	50	nA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V, I <sub>C</sub> = 0	-	-	50	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1mA	80	-	-	-
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	80	-	250	-
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA	30	-	-	-
Collector-emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 50mA, I <sub>B</sub> = 5mA	-	-	0.2	V
		I <sub>C</sub> = 10mA, I <sub>B</sub> = 1mA	-	-	0.15	V
Base-emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1mA	-	-	1	V
		I <sub>C</sub> = 50mA, I <sub>B</sub> = 5mA	-	-	1	V
Collector-base Output Capacitance	C <sub>cbo</sub>	V <sub>CB</sub> = 10V, f = 1MHz, I <sub>E</sub> = 10mA	-	-	6	pF
Current-Gain— Bandwidth Product	f <sub>T</sub>	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V f = 100MHz	80	-	-	MHz



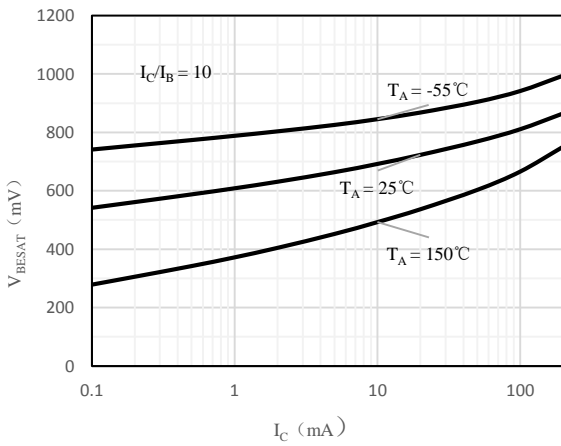
### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



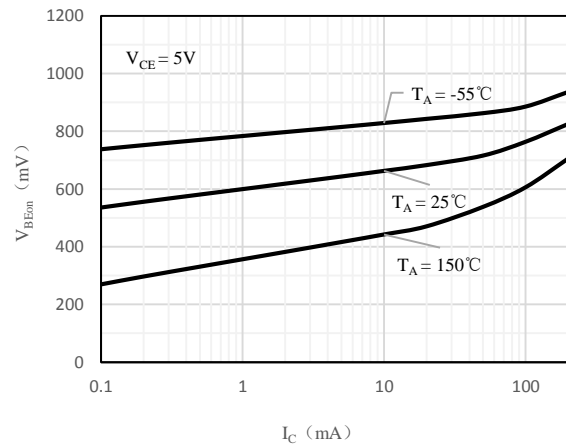
**Fig 1  $h_{FE}$  vs.  $I_C$**



**Fig 2  $V_{CE(sat)}$  vs.  $I_C$**



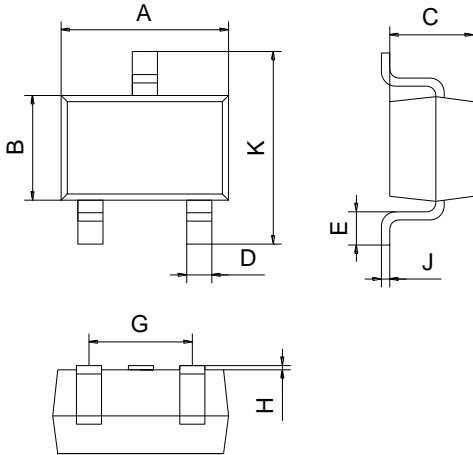
**Fig 3  $V_{BE(sat)}$  vs.  $I_C$**



**Fig 4  $V_{BE(on)}$  vs.  $I_C$**



### Package Outline Dimensions (Unit: mm)



SOT-323		
Dimension	Min.	Max.
A	2.00	2.20
B	1.15	1.35
C	0.90	1.10
D	0.15	0.35
E	0.25	0.40
G	1.20	1.40
H	0.02	0.10
J	0.05	0.15
K	2.20	2.40

### Mounting Pad Layout (Unit: mm)

#### SOT-323

